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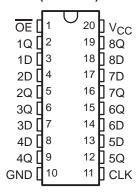
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Support Unregulated Battery Operation Down to 2.7 V
- I<sub>off</sub> and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)

#### description/ordering information

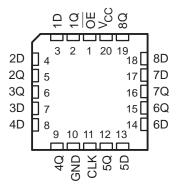
These octal flip-flops are designed specifically for low-voltage (3.3-V)  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment.

The eight flip-flops of the 'LVTH374 devices are edge-triggered D-type flip-flops. On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels set up at the data (D) inputs.

#### SN54LVTH374 . . . J OR W PACKAGE SN74LVTH374 . . . DB, DW, NS, OR PW PACKAGE (TOP VIEW)



# SN54LVTH374 . . . FK PACKAGE (TOP VIEW)



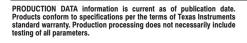
#### **ORDERING INFORMATION**

TA	PACK	AGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	0010 DW	Tube	SN74LVTH374DW	1.VT1107.4
	SOIC - DW	Tape and reel	SN74LVTH374DWR	LVTH374
-40°C to 85°C	SOP - NS	Tape and reel	SN74LVTH374NSR	LVTH374
	SSOP – DB	Tape and reel	SN74LVTH374DBR	LXH374
	TOOOD DW	Tube	SN74LVTH374PW	1.7/1/07/4
	TSSOP - PW	Tape and reel	SN74LVTH374PWR	LXH374
	CDIP – J	Tube	SNJ54LVTH374J	SNJ54LVTH374J
-55°C to 125°C	CFP – W	Tube	SNJ54LVTH374W	SNJ54LVTH374W
	LCCC - FK	Tube	SNJ54LVTH374FK	SNJ54LVTH374FK

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





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#### description/ordering information (continued)

A buffered output-enable  $(\overline{OE})$  input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

When  $V_{CC}$  is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

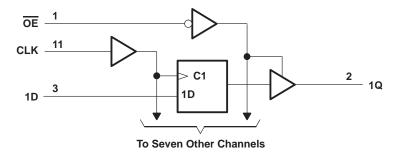
Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

These devices are fully specified for hot-insertion applications using  $I_{off}$  and power-up 3-state. The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

FUNCTION TABLE (each flip-flop)

	INPUTS	OUTPUT	
OE	CLK	D	Q
L	$\uparrow$	Н	Н
L	$\uparrow$	L	L
L	H or L	Χ	$Q_0$
Н	X	Χ	Z

#### logic diagram (positive logic)





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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, $V_{CC}$	
or power-off state, V <sub>O</sub> (see Note 1)	7 V
Voltage range applied to any output in the high state, V <sub>O</sub> (see Note 1)0.5 V to V <sub>CC</sub> + 0.5	
Current into any output in the low state, IO: SN54LVTH374	mΑ
SN74LVTH374 128 n	mΑ
Current into any output in the high state, I <sub>O</sub> (see Note 2): SN54LVTH374	mΑ
SN74LVTH374	mΑ
Input clamp current, $I_{IK}$ ( $V_I < 0$ )	mΑ
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	mΑ
Package thermal impedance, θ <sub>JA</sub> (see Note 3): DB package	:/W
DW package 58°C/	:/W
NS package 60°C/	:/W
PW package 83°C/	
Storage temperature range, T <sub>stg</sub> –65°C to 150	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  - 2. This current flows only when the output is in the high state and  $V_O > V_{CC}$ .
  - 3. The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions (see Note 4)

		SN54LV	TH374	SN74LV	TH374	LINUT
		MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage	2.7	3.6	2.7	3.6	V
V <sub>IH</sub>	High-level input voltage	2		2		V
V <sub>IL</sub>	Low-level input voltage		0.8		8.0	V
VI	Input voltage		5.5		5.5	V
IOH	High-level output current		-24		-32	mA
loL	Low-level output current		48		64	mA
Δt/Δν	Input transition rise or fall rate		10		10	ns/V
Δt/ΔV <sub>CC</sub>	Power-up ramp rate	200		200		μs/V
T <sub>A</sub>	Operating free-air temperature	-55	125	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

				SN54	4LVTH37	4	SN74	LVTH37	4		
PARA	METER	TEST Co	ONDITIONS	MIN	TYP <sup>†</sup>	MAX	MIN	TYP†	MAX	UNIT	
$V_{IK}$		$V_{CC} = 2.7 \text{ V},$	I <sub>I</sub> = -18 mA			-1.2			-1.2	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	I <sub>OH</sub> = -100 μA	V <sub>CC</sub> -0.2			V <sub>CC</sub> -0.2				
.,		$V_{CC} = 2.7 V$ ,	I <sub>OH</sub> = -8 mA	2.4			2.4			.,	
VOH		V 2V	$I_{OH} = -24 \text{ mA}$	2						V	
		VCC = 3 V	$I_{OH} = -32 \text{ mA}$				2				
		V 27V	I <sub>OL</sub> = 100 μA			0.2			0.2		
		V <sub>CC</sub> = 2.7 V	I <sub>OL</sub> = 24 mA			0.5			0.5		
\/ - ·			I <sub>OL</sub> = 16 mA			0.4			0.4	.,	
VOL		V 2)/	$I_{OL} = 32 \text{ mA}$			0.5			0.5	V	
		VCC = 3 V	I <sub>OL</sub> = 48 mA			0.55					
			I <sub>OL</sub> = 64 mA						0.55		
		$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V <sub>I</sub> = 5.5 V			10			10		
	Control inputs	V <sub>CC</sub> = 3.6 V,	$V_I = V_{CC}$ or GND			±1		±1		μА	
•	Data		$V_I = V_{CC}$			1			1	•	
	inputs	V <sub>CC</sub> = 3.6 V	V <sub>I</sub> = 0 -5						-5		
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_I$ or $V_O = 0$ to 4.5 $V$						±100	μΑ	
		VCC = 3 V	V <sub>I</sub> = 0.8 V	75			75				
I <sub>I</sub> (hold)	Data		V <sub>I</sub> = 2 V	V <sub>I</sub> = 2 V -75 -		-75			μΑ		
'I(noia)	inputs	V <sub>CC</sub> = 3.6 V <sup>‡</sup> ,	$V_{I} = 0 \text{ to } 3.6 \text{ V}$						500 -750	μι	
lozh		V <sub>CC</sub> = 3.6 V,	V <sub>O</sub> = 3 V			5			5	μΑ	
lozL		V <sub>CC</sub> = 3.6 V,	V <sub>O</sub> = 0.5 V			-5			-5	μΑ	
lozpu		$\frac{\text{V}_{\text{C}}\text{C}}{\text{OE}} = 0 \text{ to } 1.5 \text{ V, V}_{\text{O}} = 0$	0.5 V to 3 V,			±100*			±100	μΑ	
lozpd		$\frac{V_{CC}}{OE}$ = 1.5 V to 0, $V_{O}$ = $\frac{V_{CC}}{OE}$ = don't care	0.5 V to 3 V,			±100*			±100	μΑ	
		V <sub>CC</sub> = 3.6 V,	Outputs high			0.19			0.19		
ICC		$I_{O} = 0$ ,	Outputs low			5			5	mA	
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19			0.19		
ΔlCC§		V <sub>CC</sub> = 3 V to 3.6 V, On Other inputs at V <sub>CC</sub> or	e input at V <sub>CC</sub> – 0.6 V, GND			0.2			0.2	mA	
Ci		V <sub>I</sub> = 3 V or 0			3			3		pF	
Со		V <sub>O</sub> = 3 V or 0			7			7		pF	

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.



<sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

<sup>‡</sup> This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

<sup>§</sup> This is the increase in supply current for each input that is at the specified TTL voltage level, rather than VCC or GND.

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# timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			SN54L\	/TH374		SN74LVTH374				
		V <sub>CC</sub> = 3.3 V ± 0.3 V V <sub>CC</sub> =		2.7 V	$V_{CC}$ = 3.3 V $\pm$ 0.3 V		V <sub>CC</sub> = 2.7 V		UNIT	
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
fclock	Clock frequency		150		150		150		150	MHz
t <sub>W</sub>	Pulse duration, CLK high or low	3.3		3.3		3.3		3.3		ns
t <sub>su</sub>	Setup time, data before CLK↑	1.6		2		1.5		2		ns
th	Hold time, data after CLK↑	0.8		0.5		0.8		0		ns

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

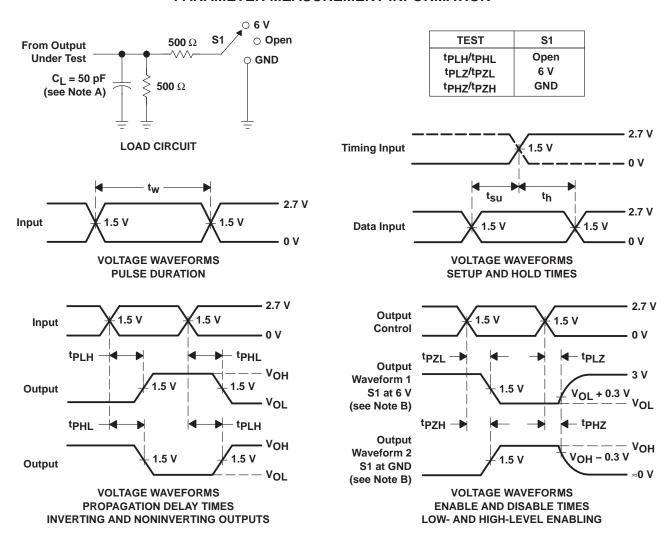
		TO (OUTPUT)		SN54LVTH374				SN74LVTH374						
PARAMETER	FROM (INPUT)		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 2.7 V		$V_{CC}$ = 3.3 V $\pm$ 0.3 V			V <sub>CC</sub> = 2.7 V		UNIT		
			MIN	MAX	MIN	MAX	MIN	TYP <sup>†</sup>	MAX	MIN	MAX			
f <sub>max</sub>			150		150		150			150		MHz		
t <sub>PLH</sub>	CLIK	0	1	5.1		5.6	1.8	2.9	4.5		5			
t <sub>PHL</sub>	CLK	Q	1.5	5.1		5.2	1.8	2.9	4.2		4.3	ns		
<sup>t</sup> PZH	ŌĒ	_	0.8	5.6		6.6	1.3	2.8	4.7		5.6			
tPZL	OE	Q	1.2	5.4		6.2	1.6	3	4.7		5.2	ns		
t <sub>PHZ</sub>	ŌĒ	Q	1.5	5.6		5.7	1.9	3	4.6	·	4.9	20		
t <sub>PLZ</sub>	OE .		Q	Q	Q	0.8	5.2		5.3	2	3.1	4.5	·	4.6

 $<sup>\</sup>uparrow$  All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.



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#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 2.5$  ns,  $t_f \leq 2.5$  ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms







4-Feb-2021

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9951001QSA	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9951001QS A SNJ54LVTH374W	Samples
SN74LVTH374DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH374	Samples
SN74LVTH374DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH374	Samples
SN74LVTH374DWE4	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH374	Samples
SN74LVTH374DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH374	Samples
SN74LVTH374NSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH374	Samples
SN74LVTH374PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH374	Samples
SN74LVTH374PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH374	Samples
SNJ54LVTH374W	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9951001QS A SNJ54LVTH374W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



### **PACKAGE OPTION ADDENDUM**

4-Feb-2021

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN54LVTH374, SN74LVTH374:

Catalog: SN74LVTH374

Enhanced Product: SN74LVTH374-EP, SN74LVTH374-EP

Military: SN54LVTH374

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

## PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH374DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH374DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVTH374NSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVTH374PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

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\*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH374DBR	SSOP	DB	20	2000	853.0	449.0	35.0
SN74LVTH374DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVTH374NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVTH374PWR	TSSOP	PW	20	2000	853.0	449.0	35.0

# W (R-GDFP-F20)

## CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

  D. Index point is provided on cap for terminal identification only.

  E. Falls within Mil—Std 1835 GDFP2—F20





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



### **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G20)

### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G20)

## PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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